

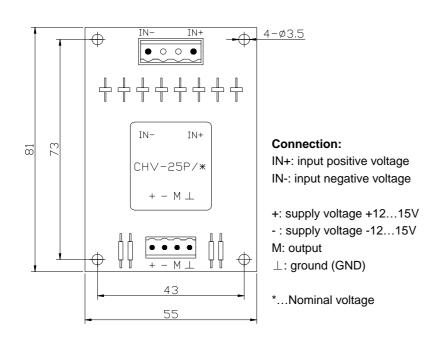
SENSOR Module CHV-25P/*

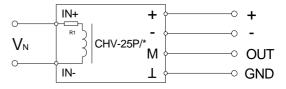
 $V_N = 50...600V$

Speci	fications: Closed lo	op Hall voltage s	ensor, Nominal	voltage 50600\	√ RMS for measu	uring of voltage: A	AC, DC, pulsed	
	Туре	CHV-25P/50	CHV-25P/100	CHV-25P/200	CHV-25P/400	CHV-25P/500	CHV-25P/600	
V_N	Nominal voltage (RMS)	50V	100V	200V	400V	500V	600V	
V_P	Measuring range(V _{P-P})	0±75V	0±150V	0±300V	0±600V	0±750V	0±900V	
R_{M}	Measuring resistance	R _M min						
	(Vc =±1215V)	>10ΚΩ						
V_{M}	Output voltage		Nominal output voltage 5V, for primary nominal voltage V_{N}					
KN	Turns ratio		2500:1000					
Χ	Accuracy		V _N ±1.0% (Ta =+25℃)					
Vc	Supply voltage		±1215V (±5%)					
Vi	Isolation voltage		Between primary and secondary circuit: 2.5KV RMS/50Hz/1min.					
Voff	Offset voltage	±30mV max, for primary voltage V _N =0 (Ta =+25℃)						
Td	Temperature drift	V _M of 0.05%/℃ (-25℃…+70℃)						
L	Linearity		0.1%					
Tr Response time 40µS								
	di/dt							
f	Frequency bandwidth	020KHz						
Та	Operating temperature	-25℃+70℃						
Ts	Storage temperature	-40℃+90℃						
lc	Current consumption	10mA+I _M (Output current)						
Rs	Secondary resistance	110Ω (Ta =+70℃)						
R_N	Primary resistance	250Ω+R1 (Build in resistor) (Ta =+70°C)						
W	Weight	50g						

Dimensions (mm):

Connection:







- 1. Output V_{M} is positive, when a positive voltage V_{N} is applied on the terminal IN+.
- 2. The sensor is directly connected to the primary voltage V_{N} by the terminals IN+ and IN- (R1 is built into the sensor.)





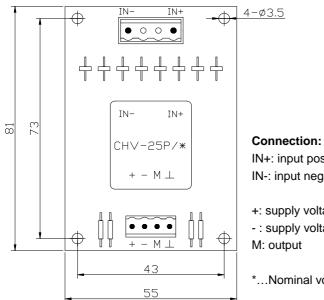
SENSOR Module CHV-25P/*A

 $V_N = 50...600V$

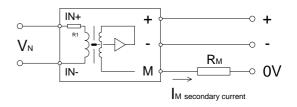
Specifications: Closed loop Hall voltage sensor, Nominal voltage 50600V RMS for measuring of voltage: AC, DC, pulsed							
	Туре	CHV-25P/50A	CHV-25P/100A	CHV-25P/200A	CHV-25P/400A	CHV-25P/500A	CHV-25P/600A
V_N	Nominal voltage (RMS)	50V	100V	200V	400V	500V	600V
V_P	Measuring range (V _{P-P})	0±75V	0±150V	0±300V	0±600V	0±750V	0±900V
KN	Turns ratio	2500	00:1000 5000:1000				
R_{M}	Measuring resistance	R_M min		R _M max			
	(Vc =±1215V)	Ω		350Ω			
I _M	Output current		Nominal output current 25mA, for primary nominal voltage V _N				
Χ	Accuracy			V _N ±1.0% (Га =+25°С)		
Vc	Supply voltage		±1215V (±5%)				
Vi	Isolation voltage	Between primary and secondary circuit: 2.5KV RMS/50Hz/1min.					
loff	Offset current	±0.2mA max, for primary voltage V_N =0 (Ta =+25 $^{\circ}$ C)					
Td	Temperature drift	I _M of 0.05%/℃ (-25℃…+70℃)					
_L	Linearity	0.1%					
Tr	Response time	40μS					
	di/dt						
f	Frequency bandwidth	020KHz					
Та	Operating temperature	-25℃…+70℃					
Ts	Storage temperature	-40°C+90°C					
lc	Current consumption	10mA+I _M (Output current)					
Rs	Secondary resistance	110Ω(Ta =+70℃)					
R_N	Primary resistance	250Ω+R1 (Build in resistor) (Ta =+70℃)					
W	Weight	50g					

Dimensions (mm):

Primary voltage V_{N}



Connection:



IN+: input positive voltage IN-: input negative voltage

- +: supply voltage +12...15V
- -: supply voltage -12...15V

M: output

*...Nominal voltage



- 1. Output I_M is positive, when a positive voltage V_N is applied on the terminal IN+.
- 2. The sensor is directly connected to the primary voltage V_N by the terminals IN+ and IN- (R1 is built into the sensor.)
- 3. A voltage output V_M is obtained by connecting a resistor R_M between M and 0V.





基第SENSOR Module CHV-50P/*

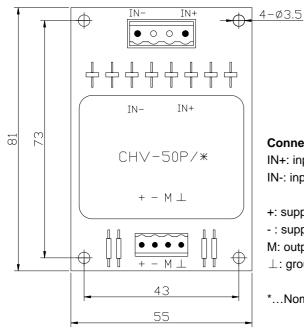
$V_N = 100...1000V$

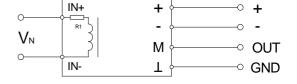
Specifications: Closed loop Hall voltage sensor, Nominal voltage 100...1000V RMS for measuring of voltage: AC/DC/pulsed

	.		<u> </u>				
	Туре	CHV-50P/100	CHV-50P/400	CHV-50P/800	CHV-50P/1000		
V_N	Nominal voltage (RMS)	100V	400V	800V	1000V		
V_P	Measuring range(V _{P-P})	0±150V	0±600V	0±1200V	0±1500V		
R_{M}	Measuring resistance	R _M min					
	(Vc =±1215V)						
V_{M}	Output voltage	Nominal output voltage 5V, for primary nominal voltage V _N					
K _N	Turns ratio	5000:1000					
Χ	Accuracy	V _N ±0.8% (Ta =+25℃)					
Vc	Supply voltage	±12V15V (±5%)					
Vi	Isolation voltage	Between primary and secondary circuit: 3KV RMS/50Hz/1min.					
Voff	Offset voltage	±30mV max, for primary voltage V _N =0 (Ta =+25℃)					
Td	Temperature drift	V _M of 0.05%/℃ (-25℃+70℃)					
L	Linearity	0.2%					
Tr	Response time	40200μS					
f	Frequency bandwidth	020KHz					
Та	Operating temperature	-25℃+70℃					
Ts	Storage temperature	-25℃+85℃					
lc	Current consumption	10mA+I _M (Measuring current)					
Rs	Secondary resistance	30Ω (Ta =+70℃)					
R_N	Primary resistance	500Ω+R1 (Build in resistor) (Ta =+70℃)					
W	Weight	110g					

Dimensions (mm):

Connection:





Connection:

IN+: input positive voltage IN-: input negative voltage

- +: supply voltage +12...15V
- -: supply voltage -12...15V
- M: output
- \perp : ground (GND)
- *...Nominal voltage



- 1. Output V_{M} is positive, when a positive voltage V_{N} is applied on the terminal IN+.
- 2. The sensor is directly connected to the primary voltage V_{N} by the terminals IN+ and IN- (R1 is built into the sensor.)





SENSOR Module CHV-50P/*A

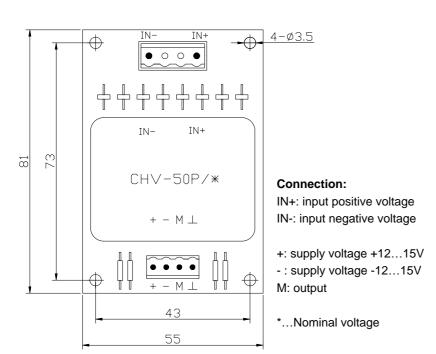
 $V_N = 100...1000V$

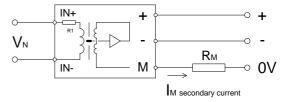
Specifications: Closed loop Hall voltage sensor, Nominal voltage 100...1000V RMS for measuring of voltage: AC, DC, pulsed

	Туре	CHV-50P/100A	CHV-50P/400A	CHV-50P/800A	CHV-50P/1000A	
V_N	Nominal voltage (RMS)	100V	400V	800V	1000V	
V_P	Measuring range	0±150V	0±600V	0±1200V	0±1500V	
R_{M}	Measuring resistance	R _M min		R _M max		
	(Vc =±1215V)	0	Ω	350Ω		
I_{M}	Output current	Nominal output current 25mA, for primary nominal voltage V _N				
K_N	Turns ratio	5000:1000 10000				
Χ	Accuracy	V _N ±0.8% (Ta =+25℃)				
Vc	Supply voltage	±1215V (±5%)				
Vi	Isolation voltage	Between primary and secondary circuit: 3KV RMS/50Hz/1min.				
loff	Offset current	±0.3mA max, for primary voltage V _N =0 (Ta =+25 °C)				
Td	Temperature drift	I _M of 0.05%/℃ (-25℃…+70℃)				
_L	Linearity	0.2%				
Tr	Response time	40200μS				
<u>f</u>	Frequency bandwidth	020KHz				
Ta	Operating temperature	-25℃+70℃				
Ts	Storage temperature	-25 ℃ +85 ℃				
Ic	Current consumption	10mA+I _M (Measuring current)				
Rs	Secondary resistance	30Ω (Ta =+70°C)				
R_N	Primary resistance	500Ω+R1 (Build in resistor) (Ta =+70°C)				
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Dimensions (mm):

Connection:







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